MA3SD29F

Silicon epitaxial planar type

For super high speed switching circuits

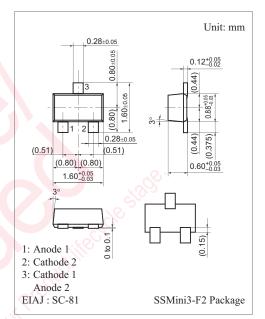
■ Features

- Low forward voltage V_F : < 0.42 V (at I_F = 100 mA)
- Optimum for high-frequency rectification
- Short reverse recovery time t_{rr}

■ Absolute Maximum Ratings $T_a = 25$ °C

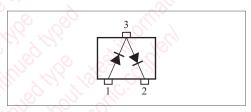
Parameter	Symbol	Rating	Unit		
Reverse voltage		V_R	30	V	
Repetitive peak reverse voltage		V _{RRM}	30	V	
Forward current (Average)	Single	T	100	mA	
	Series	$I_{F(AV)}$	75		
Peak forward current	Single	Ţ	200		
	Series	I_{FM}	150	mA	
Non-repetitive peak forward surge current *		I _{FSM} 1		A	
Junction temperature	T _j	125	°C		
Storage temperature	T _{stg}	-55 to +125	°C		

Note) *: 50 Hz sine wave 1 cycle (Non-repetitive peak current)



Marking Symbol: M5R

Internal Connection



■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V_{F1}	$I_F = 10 \text{ mA}$		0.25	0.29	V
	V_{F2}	$I_F = 100 \text{ mA}$		0.39	0.42	
Reverse current	I_{R1}	$V_{R^l} = 10 \text{ V}$			25	μΑ
	I_{R2}	$V_{R^I} = 30 \text{ V}$			120	
Terminal capacitance	C_{t}	$V_{Rl} = 0 V, f = 1 MHz$		11		pF
Reverse recovery time *	t _{rr}	$I_F = I_{Rl} = 100 \text{ mA}, I_m = 10 \text{ mA},$ $R_{Ll} = 100 \Omega$		1		ns

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

- 2. Absolute frequency of input and output is 250 MHz
- 3. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 4. *: t_{rr} measurement circuit

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